#### TCXO2520S-&\* MHz-A-V High Stability TCXO

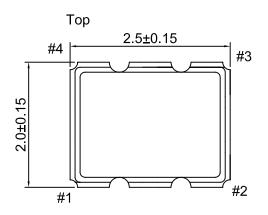
#### **Features and Benefits**

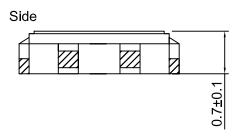
Better than ±0.5ppm from -40°C to +85°C 3.0V supply; 1.5mA maximum Less than -135dBc/Hz @ 1KHz offset

## **Typical Applications**

Mobile Radio Communication Equipment

## **Mechanical Drawing & Pin Connections**



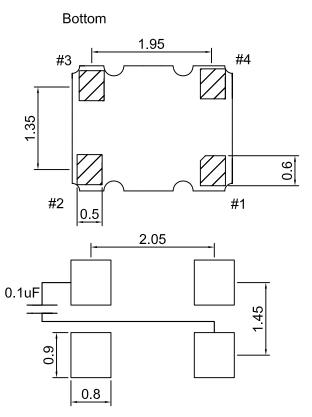


Pin Connection

Pin	Function			
#1	VCON			
#2	GND			
#3	Output			
#4	Vdd			

Unit: mm 1mm=0.0394inch

#### Drawing No:MD160110-1



Recommened soldering pattern



# Dynamic Engineers Inc.

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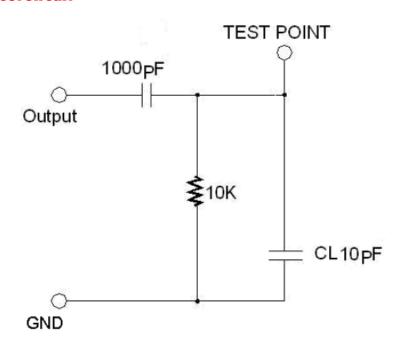
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## **Specifications**

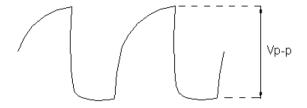
Oscillator	Sym	Condition		Value		Unit	Note	
Specification		Condition	Min.	Тур.	Max.			
Nominal Frequency	$F_0$			26.00		MHz		
RF Output			•					
Output Wave Form		DC Coupled clipped sine wave	Clip	ped Sine	Wave			
Voltage Level			8.0			Vp-p		
Load				10 10		Kohm pF		
Start Up Time					2.0	ms		
Power Supply								
Voltage	V <sub>cc</sub>		2.85	3.00	3.15	V		
Current		At maximum supply voltage			1.5	mA		
Control Voltage								
Control Voltage Range			ÁÁO	1.5	3.0	V		
Pulling Range		Referenced to VCON at 1.5V	±5			ppm		
Vcon Input Impedance		Measured between VCON and GND pin	500			kOhm		
Linearity					10	%		
Frequency Stability								
Nominal Frequency Tolerance		Frequency @ +25°C	-2.0		+2.0	ppm	1 hour after 2 times reflow	
Over Temperature		-40°C to +85°C	-0.5		+0.5	ppm	Referenced to the midpoint between minimum and maximum frequency value	
Supply Voltage Change		Supply voltage varied ±5% at 25°C	-0.2		+0.2	ppm		
Load Sensitivity		±10% load change	-0.2		+0.2	ppm		
Aging		1 <sup>st</sup> year at 25°C	-1.0		+1.0	ppm		
Phase Noise								
Phase noise		100 Hz offset		-115		dDa/U-		
		1 kHz offset		-135				
		10 kHz offset		-150		dBc/Hz		
		100 kHz offset		-152				
<b>Environmental Conditio</b>	ns							
Parameter		Test Conditions		Reference Std.				
Operating temperature ra	•		-40°C to +85°C					
Storage temperature range				-40°C to +85°C				
each axis for 4 hou		10-2000Hz, 1.52mm, 2 each axis for 4 hours	•	MIL-STD-883 2007 Condition A JESD22-B103 Condition 1				
Thermal Shock		-55°C, 125°C; soak tim 10 mins, with total 200 cycles	MIL-STD-883-1010 Condition B JESD22-A104 Condition B					
Mechanical Shock		1500G, half-sine, 0.5m each axis for 3 times	ıs,	MIL-STD-883-2002 Condition B JESD22-B104 Condition B				

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# **Test Circuit**

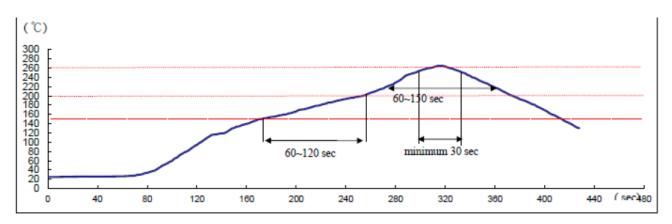


# **Output Waveform**



#### **Recommended IR Reflow Profile**

IR reflow profile of ceramic SMD products for Pb free process



Reference Standard: JEDEC-STD020

Test Conditions: Pre-heating: 150°C to 200°C, 60~120secs

Heating: 217°C, 60~150secs

Peak temperature at least: 260°C, the time above 255°C, minimum 30 sec